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Large-area vertically aligned 2D MoS₂ layers on TEMPO-cellulose nanofibers for biodegradable transient gas sensors

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Abstract

Crystallographically anisotropic two-dimensional (2D) molybdenum disulfide (MoS₂) with vertically aligned (VA) layers is attractive for electrochemical sensing owing to its surface-enriched dangling bonds coupled with extremely large mechanical deformability. In this study, we explored VA-2D MoS₂ layers integrated on cellulose nanofibers (CNFs) for detecting various volatile organic compound gases. Sensor devices employing VA-2D MoS₂/CNFs exhibited excellent sensitivities for the tested gases of ethanol, methanol, ammonia, and acetone; e.g. a high response rate up to 83.39% for 100 ppm ethanol, significantly outperforming previously reported sensors employing horizontally aligned 2D MoS₂ layers. Furthermore, VA-2D MoS₂/CNFs were identified to be completely dissolvable in buffer solutions such as phosphate-buffered saline solution and baking soda buffer solution without releasing toxic chemicals. This unusual combination of high sensitivity and excellent biodegradability inherent to VA-2D MoS₂/CNFs offers unprecedented opportunities for exploring mechanically reconfigurable sensor technologies with bio-compatible transient characteristics.

Supplementary material for this article is available [online](#)

Keywords: 2D MoS₂, cellulose nanofiber, flexible device, transient device, gas sensor

(Some figures may appear in colour only in the online journal)

1. Introduction

Transient electronics represents a concept of emerging device technologies with distinctive advantages of improved biological and environmental benignity over conventional approaches [1–3]. In this approach, electronic devices are programmed to be completely disintegrated and transformed into bio-compatible forms upon completing their targeted

functions. This transient process is performed in a renewable and recyclable manner, minimally impacting the environment, thus, mitigating the prevalent issue of ‘electronic wastes’; i.e. conventional electronic devices are irreversibly disposed and their continued accumulation demands a substantial amount of landfill spaces imposing environmental threats [4–7]. A variety of electronic devices with transient characteristics have been demonstrated for a wide range of applications,

including photovoltaics [8], transistors [9], and medical devices [10, 11]. This idea can be further facilitated by exploring novel inorganic and/or organic materials with essential transient characteristics such as biocompatibility and excellent electrical properties [12–14]. In this regard, recently explored near atom-thickness 2D MoS₂ layers are uniquely promising, owing to their structural, chemical, and electrical superiority. In addition to their property advantages, such as high carrier mobility, they are known to be dissolvable in bio-friendly solutions without releasing any toxic chemicals [15–17]. A combination of these unique yet outstanding characteristics can lead to a variety of novel applications, particularly utilizing their intrinsic capability of detecting various gas species [18–24]. Furthermore, their anisotropic crystallinity allows them to be chemically grown in a vertically aligned (VA) orientation exposing 2D layer edges on their surfaces accompanying mechanical flexibility [18]. These edges-exposed surfaces are chemically reactive due to ample dangling bonds and well suited to electrochemical sensing applications, including the detection of volatile organic compound (VOC) gases [25–28]. Despite the above-projected opportunities, studies on applying transient VA-2D MoS₂ layers for VOC gas sensing remain unavailable.

Herein, we report on VA-2D MoS₂ layers-based VOC gas sensors by employing their high gas sensitivity, excellent mechanical flexibility, and intrinsic transient features. We directly integrated centimeter-scale VA-2D MoS₂ layers onto biodegradable, transparent, and deformable cellulose nanofibers (CNFs) [29–32]. Particularly, 2,2,6,6-tetramethylpiperidine-1-oxyl (TEMPO)-oxidized CNFs, namely TOCNs, were employed owing to their unique advantages such as low density, high stiffness, and large specific surface area [14, 30, 33–35]. VA-2D MoS₂ layers integrated on TOCNs exhibited excellent performance in sensing various VOC gases. For instance, high sensitivity of 83.39% was observed with 100 ppm ethanol, significantly outperforming previously reported sensors based on horizontally aligned 2D MoS₂ layers. Furthermore, the sensors employing VA-2D MoS₂/TOCNs were demonstrated to dissolve in bio-friendly buffer solutions completely. This dissolution was identified to involve the conversion of MoS₂ to non-toxic molybdenum oxide (MoO_x), further confirming the biocompatible transient characteristics of the sensors.

2. Experimental methods

2.1. Chemical vapor deposition (CVD) growth of centimeter-scale VA-2D MoS₂ layers

Mo thin films (6 nm thickness) were deposited on silicon dioxide (300 nm thickness) /silicon (SiO₂/Si) substrates by an e-beam evaporator (Thermionics VE-100) at a deposition rate of $\sim 0.05\text{--}0.12\text{ }\text{\AA}\text{ s}^{-1}$ and at a chamber base pressure of $\langle 5.5 \times 10^{-6}$ Torr. The Mo-deposited substrates were placed at the center of a CVD furnace chamber (Lindberg/Blue M Mini-Mite) along with sulfur (S) powder ($\geq 99.5\%$, Sigma-Aldrich) placed on an alumina boat on the furnace's upstream

side. The CVD chamber was pumped down to 40 mTorr, and ultra-pure Ar gas was supplied at a flow rate of 100 sccm (standard cubic centimeter per minute). Subsequently, the CVD furnace was heated up to 800 °C in ~ 50 min and was maintained at that temperature for another ~ 50 min, followed by natural cooling down to room temperature.

2.2. Preparation of TOCN substrates and integration of VA-2D MoS₂ layers onto them

Commercially available slurry TOCNs (CELLULOSELAB, width of ~ 50 nm and length of $>$ several hundred μm) in water (1 wt%) were mixed with deionized (DI) water followed by sonication for 1–2 h. The prepared well-dispersed TOCN suspension (0.5 wt%) was directly poured onto as-grown VA-2D MoS₂ layers on SiO₂/Si substrates, followed by room-temperature drying for ~ 48 h until it turned into a transparent paper. Then, the TOCN-integrated VA-2D MoS₂ layers were manually peeled off from their growth SiO₂/Si substrates.

2.3. Material characterization

Raman spectral characterization was performed with Nano-finder 30 Raman Confocal spectroscopy (Tokyo Instrument Inc.) using a laser source with a wavelength of 532 nm and a spot size of 1 μm . Scanning electron microscope (SEM) characterization was carried out using Hitachi SU8230 at an accelerating voltage of 15 kV with 1 nm resolution. Transmission electron microscope (TEM) characterization was performed with Cs-corrected JEOL ARM 200F at an acceleration voltage of 200 kV. X-ray photoelectron spectroscopy (XPS) characterization was performed with Thermo Scientific ESCALAB 250Xi photoelectron spectrometer using an aluminum (Al) anode as the x-ray source (1486.68 eV). X-ray diffraction (XRD) patterns were measured using Empyrean PANalytical.

2.4. Gas sensing measurement

For the VOC gas sensing measurement, VA-2D MoS₂/TOCN sensors were connected to the resistance measurement equipment (Keithley 2400 source meter) in a closed test chamber (Supplementary information, figure S1 (available online at stacks.iop.org/NANO/33/475502/mmedia)). For the VOC gas injection, the total gas flow was fixed to 40 sccm by combining a mixture of pure nitrogen, pure oxygen, and target gas diluted in nitrogen. The gas carrier is bubbled through the liquid analyte of interest for the gas injection and subsequently mixed with the diluted air in the test chamber. For analyte gas bubbling, the synthetic air comprising 80 sccm of nitrogen and 20 sccm of oxygen gas was continuously blown into the chamber. The resistance of the sensors was recorded by using a customized LabVIEW program under a periodic supply of the target gas.

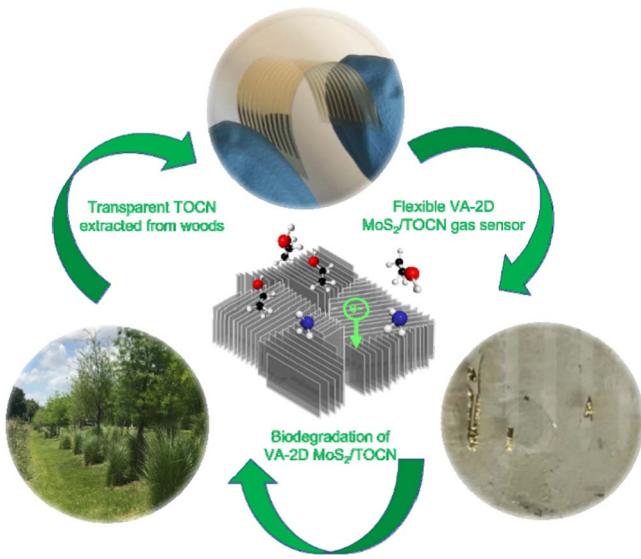


Figure 1. Conceptual illustration of flexible VA-2D MoS₂ layers integrated on TOCN substrates for VOC sensing applications and their biodegradable, transient characteristics.

2.5. Biodegradable dissolution of VA-2D MoS₂/TOCN

Two different buffer solutions (0.1 M) were prepared by dissolving commercially available phosphate-buffered saline (PBS: Sigma Aldrich, pH 7.4, 0.926g) in DI water (100 ml) and dissolving baking soda (NaHCO₃, 0.845 g) in DI water (100 ml). VA-2D MoS₂/TOCN sensors with gold (Au) electrodes were placed inside the prepared buffer solutions at 75 °C (hotplate) and were sealed to prevent their rapid evaporation. The samples were taken out of the solutions for ~20 min for optical microscope observations and the solutions were replaced every 2 d to maintain the same concentration.

3. Results and discussions

Figure 1 presents a conceptual illustration of the likely life cycle of flexible VA-2D MoS₂ layers integrated on TOCN substrates and their biodegradable, transient characteristics. Biodegradable, transparent, and flexible TOCNs are extracted from wood pulps, and they can be naturally biodegraded via fungal biodegradation without causing any deleterious impacts on the environment [14]. VA-2D MoS₂ layers are integrated onto the TOCNs with Au electrode stripes, and they are utilized for VOC gas sensing applications. The gas sensor devices are dissolved via buffer solutions after completing their target functions and are recycled into the environment in an environmentally benign manner. Recently, a variety of *in vivo* and *in vitro* studies indicate the intrinsic biodegradability and biocompatibility of 2D MoS₂ layers; i.e. intrinsically low cytotoxicity was observed in 2D MoS₂ layers when interacting with human cells [36–40], which enabled their application for gene delivery vehicles in biological systems [41–44]. Furthermore, the dissolution of 2D MoS₂ layers in buffer solutions was identified to be bio-friendly

[15, 17], which justifies their incorporation into biodegradable TOCNs for the conceptually proposed VOC gas sensors with transient characteristics. The illustration in the center of figure 1 presents a schematic view of VA-2D MoS₂ layers interacting with gas molecules which are adsorbed onto their surface with ample layer edge sites.

Figure 2(a) shows a schematic illustration of the fabrication process of a VA-2D MoS₂/TOCN gas sensor. The fabrication starts with the wafer-scale CVD growth of the VA-2D MoS₂ layers with a typical lateral dimension of ~10 cm × 2 cm on top of a SiO₂/Si wafer [15, 45–49]. Mo film of a controlled thickness (~6 nm) is deposited on a clean SiO₂/Si wafer via electron beam evaporation followed by the CVD sulfurization reaction, which converts the Mo films into VA-2D MoS₂ layers, as previously demonstrated [18, 50, 51]. Detailed CVD growth procedures are described in the experimental methods section. Subsequently, TOCN suspension in DI water is drop-casted on the VA-2D MoS₂ layers grown on SiO₂/Si, following the previously developed recipe [15, 45] as described in the experimental methods section. After air-drying at room temperature for ~48 h, the TOCN-covered VA-2D MoS₂ layers are manually peeled off from the SiO₂/Si wafer [15, 46]. Lastly, Au electrodes in stripe shapes are deposited on top of the VA-2D MoS₂ layers for subsequent electrical measurements. Figure 2(b) shows images of the direct drop-casting of TOCN suspension onto VA-2D MoS₂ layers grown on a SiO₂/Si sample (left) and a manually peeled VA-2D MoS₂/TOCN sample and its original SiO₂/Si wafer (right). Figure 2(c) presents images of a completely fabricated VA-2D MoS₂/TOCN gas sensor in its pristine (left) and bent (right) state, confirming its mechanical flexibility. Figure 2(d) shows the Raman spectroscopy profile obtained from the sample in figure 2(c), revealing the characteristic peaks of VA-2D MoS₂ layers corresponding to the in-plane ($E_{2g}^{1,}$ at 381 cm⁻¹) and out-of-plane (A_{1g} , at 407 cm⁻¹) vibration modes. The low peak intensity ratio, i.e. $E_{2g}^{1,}/A_{1g}$ of ~0.5, indicates the dominance of the A_{1g} vibration mode owing to the pronouncedly exposed layer edge sites on the sample surface, consistent with previous studies [47, 48, 52]. Figure 2(e) shows SEM images of an as-prepared TOCN film before (top) and after (bottom) the integration of VA-2D MoS₂ layers, confirming its continuous film morphology. The corresponding higher magnification SEM images are presented in Supplementary Information, figure S2. Figure 2(f) shows energy-dispersive x-ray spectroscopy (EDS) mapping images of Mo and S elements obtained from the sample in figure 2(b), confirming their spatial homogeneity. Figure 2(g) shows a plain-view high-resolution transmission electron microscopy (HRTEM) image of as-grown VA-2D MoS₂ layers unveiling their surface-exposed 2D layer edges sites, consistent with previous studies [18, 47, 50, 52–54]. The measured lattice spacing of ~0.62 nm confirms the presence of highly-dense surface-exposed van der Waals (vdW) gaps. The corresponding fast Fourier-transform image shows a (002) diffraction ring, further indicating predominantly surface-exposed vdW gaps, as presented in Supplementary information, figure S3. Additionally, an XRD pattern obtained from VA-2D MoS₂ layers

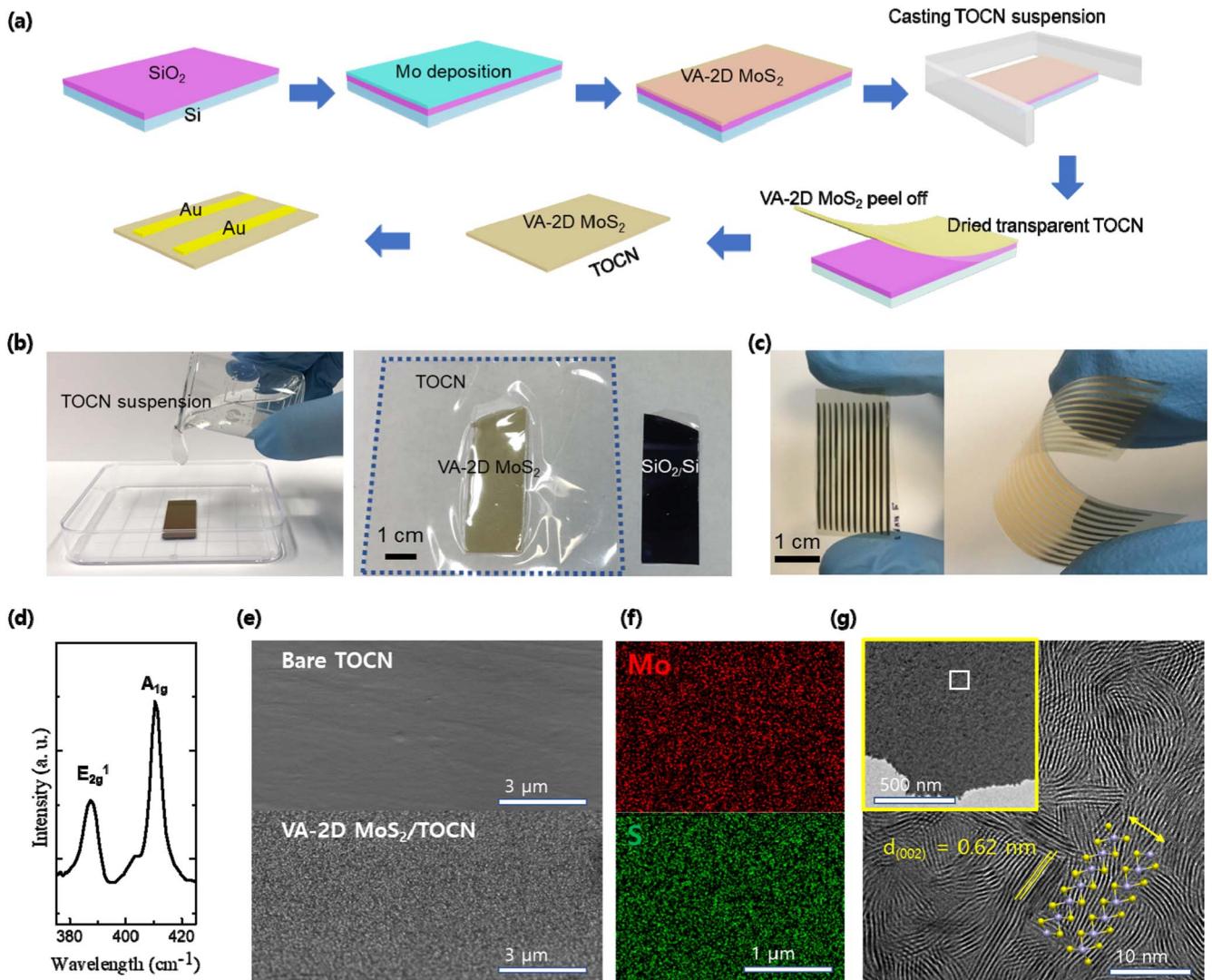


Figure 2. Material preparation and characterization of VA-2D MoS₂ layers integrated on TOCN substrates. (a) Schematic illustration of the fabrication process of VA-2D MoS₂/TOCN gas sensor. (b) Camera images of TOCN suspension drop-casting on VA-2D MoS₂ layers grown on a SiO₂/Si substrate (left) and integrated VA-2D MoS₂ layers on dried TOCN (right). (c) Optical images of VA-2D MoS₂/TOCN sensor with Au electrodes in its pristine (left) and bent (right) state. (d) Raman spectrum of the sample in (c) showing characteristic peaks of VA-2D MoS₂ layers. (e) SEM images of a bare TOCN (top) and VA-2D MoS₂ integrated on it (bottom). (f) SEM-EDS elemental maps showing the spatial distribution of Mo and S in VA-2D MoS₂ layers. (g) Plain-view HRTEM image of VA-2D MoS₂ layers revealing layer edge sites and its corresponding low magnification image (inset).

grown on a SiO₂/Si wafer before their integration on TOCN is presented in Supplementary Information, figure S4.

Figures 3(a)–(d) present the dynamic gas-sensing performances of a VA-2D MoS₂/TOCN sensor tested with four different VOC gases of methanol, ethanol, acetone, and ammonia. The VA-2D MoS₂/TOCN sensor was periodically exposed to the gases of constant 100 ppm for 5 min under an ambient atmosphere at room temperature, and its base resistance was \sim 40 k Ω . After the introduction of each gas, the sensor was exposed to a flow of clean air composed of nitrogen (80 sccm) and oxygen (20 sccm) to recover its base resistance. During the introduction of all tested gases, the sensor exhibited an increase in its resistance which returned to the base value within 5 min upon their termination. The sensor reliably responded to the three repeated ON/OFF gas cycles, confirming its excellent sensitivity and reproducibility.

Response/recovery times are commonly adopted to identify the proficiency of sensors, which are defined by the timelines where they reach 90% of total resistance changes [20, 55]. The average response/recovery times are determined to be in a range of \sim 100 to \sim 300 s for our tested VOC gases, as presented in Supplementary information, figure S5. CVD-grown VA-2D MoS₂ layers are known to exhibit p-type semiconducting characteristics, as verified in previous studies [18, 56, 57]. Given all the tested gases are known to be electron donor molecules [58, 59], they tend to transfer electrons to the VA-2D MoS₂ layers upon being adsorbed onto the surface-exposed layer edge sites. Accordingly, the concentration of charge carriers (i.e. hole concentration) on the surface of the VA-2D MoS₂ layers decreases, leading to the increased resistance of the sensor. This resistance increase introduced by the electron-donating VOC gases is opposite to

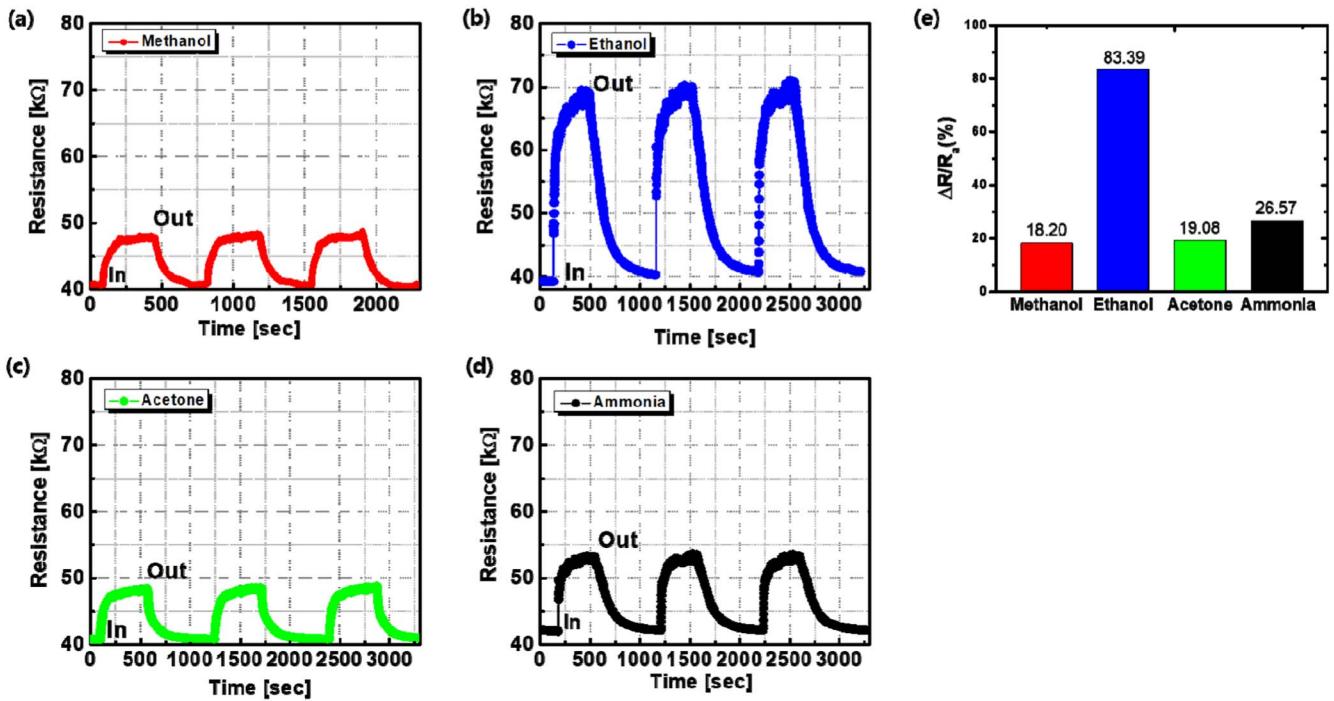


Figure 3. VOC gas sensing demonstrations with VA-2D MoS₂/TOCNs under a cyclic introduction of 100 ppm (a) methanol, (b) ethanol, (c) acetone, and (d) ammonia. (e) Calculated average gas response for each gas.

the observation with the electron-accepting nitrogen dioxide (NO₂) gas, which indeed decreased the resistance of VA-2D MoS₂ layers, as previously reported [18]. Figure 3(e) compares the calculated average gas response for each gas presented by the relative ratio of resistance, i.e. $\Delta R/R_a = (R_{\text{gas on}} - R_a)/R_a$ where ΔR is the resistance change caused by the gas, $R_{\text{gas on}}$ is the resistance when the gas was introduced, and R_a is the base resistance under the ambient air. The gas response was identified to be 18.20%, 83.39%, 19.08%, and 26.57% for methanol, ethanol, acetone, and ammonia, respectively. It is noteworthy that this VA-2D MoS₂ layers-based sensor exhibited the highest gas response of 83.39% with ethanol gas. This responsitivity value is indeed much higher than those observed with horizontally-aligned 2D MoS₂ layers-based sensors employed for sensing 100 ppm ethanol gas in previous studies [19, 23, 24], confirming the structural advantage of VA-2D MoS₂ layers. While the exact clarification of the origin for this superior ethanol sensitivity in VA-2D MoS₂ layers needs further investigation, several possible mechanisms are proposed. For instance, the presence of high-density ($-\text{CH}_2-$)_n chains within ethanol is suggested to be responsible for its facile surface decomposition, resulting in a more efficient transfer of electrons than methanol [60]. This was verified by density functional theory (DFT) studies which confirmed the negative adsorption energy of ethanol and various VOC gases, including methanol, suggesting its easier electrochemical detection [20]. This strong binding affinity of ethanol was further facilitated by the high *d*-orbital electron density of 2D MoS₂ layer edge sites inherent to VA-2D MoS₂ layers, as previously demonstrated in additional DFT studies [53].

Having confirmed the excellent sensitivity of VA-2D MoS₂/TOCN gas sensors, we focused on unveiling their biodegradable transient characteristics. As 2D MoS₂ layers are known to be water-insoluble [61] and highly stable under ambient conditions [62–65], we attempted to dissolve VA-2D MoS₂ layers in two different bio-friendly buffer solutions of PBS and BSB [15–17]. Details for the preparation of these buffer solutions and the dissolution experiments are presented in the experimental methods section. Figure 4(a) shows time-lapse images of VA-2D MoS₂/TOCN with Au electrodes undergoing dissolution in PBS solution (100 ml of 0.1 M) set at 75 °C with pH ~6.7. The top camera images reveal that VA-2D MoS₂ layers gradually disintegrate with increasing time and become completely dissolved after ~6 d, and the bottom optical microscope images present the corresponding enlarged views of their progressive disintegration. Figure 4(b) shows a camera image of the PBS solution containing the dissolved VA-2D MoS₂ layers after 6 d, revealing some fragmented Au electrode residuals. Figure 4(c) shows time-lapse images of VA-2D MoS₂/TOCN with Au electrodes undergoing dissolution in the BSB solution composed of sodium bicarbonate (NaHCO₃) mixed with DI water (100 ml of 0.1 M) at 75 °C with pH ~8.3. The images reveal the transient characteristics of VA-2D MoS₂/TOCN, similar to the observation with PBS solution in figure 4(a). Figure 4(d) shows a camera image of the BSB solution containing the dissolved VA-2D MoS₂ layers after 6 d, revealing similar characteristics observed with PBS solution (figure 4(b)). In both figures 4(a) and (c), it is noted that the cracks formed on the surfaces of VA-2D MoS₂ layers after ~24 h of exposure to buffer solutions serve as the reaction starting points spreading towards outer regions, which is an indication of

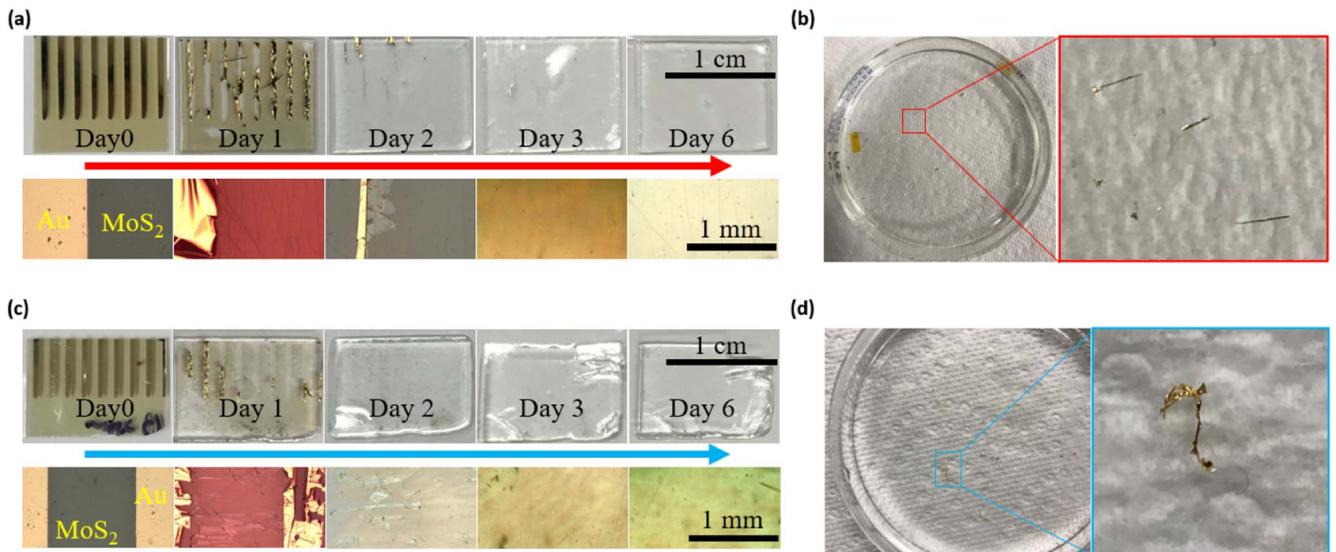


Figure 4. Demonstration of biodegradable transient characteristics. (a) Dissolution of VA-2D MoS₂/TOCN with Au electrodes in PBS solution at 75 °C. (b) Residual Au electrodes in PBS solution after 6 d. (c) Dissolution of VA-2D MoS₂/TOCN with Au electrodes in BSB solution at 75 °C. (d) Residual Au electrodes in BSB solution after 6 d.

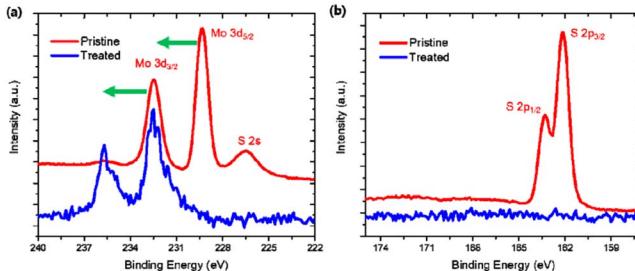


Figure 5. XPS spectra obtained from VA-2D MoS₂ layers before (red lots) and after (blue plots) their dissolution in BSB solution, denoting peak shifts of (a) Mo 3d and S 2s (b) S 2p core levels.

defect-accelerated degradation [12, 17]. Potassium/sodium ions (K^+ / Na^+) contained in PBS and Na^+ in BSB solutions are known to distort the lattice of 2D MoS₂ layers via intercalation into their vdW gaps, and subsequently form soluble potassium/sodium sulfides (K_2S/Na_2S) and molybdenum di/trioxides (MoO_2/MoO_3) [12, 15, 17, 66].

In order to clarify the dissolution chemistry and mechanism of VA-2D MoS₂ layers in buffer solutions, we employed x-ray photoelectron spectroscopy (XPS) to characterize their oxidation states. Figure 5 shows XPS spectra obtained from VA-2D MoS₂ layers before and after their exposure to BSB solution. Figure 5(a) compares XPS peaks corresponding to Mo 3d and S 2s core levels obtained from an identical sample in its pristine state (red plot) and after being treated with BSB solution for 8 d (blue plot). The sample in its pristine state exhibits peaks at 232.5, 229.3, and 226.5 eV, which correspond to Mo 3d_{3/2}, Mo 3d_{5/2}, and S 2s, respectively. Meanwhile, it exhibits a noticeable shift of Mo peaks, i.e. located at 235.7 and 232.5 eV, which indicates a stoichiometric change of Mo (IV) to Mo (V) oxidation state, similar to previous observations [15]. Figure 5(b) compares XPS peaks corresponding to S 2p core levels obtained from the same sample before/after its BSB treatment. The pristine

sample exhibits two characteristic peaks at 163.3 and 162.1 eV corresponding to S 2p_{1/2} and S 2p_{3/2}, respectively, indicating a presence of stoichiometric sulfide (S^{2-}) in VA-2D MoS₂ layers. These sulfide peaks completely disappear after the treatment, which, together with the XPS spectra of figure 5(a), confirms the conversion of stoichiometric MoS₂ to bio-friendly MoO_x. In addition to confirming the dissolution of VA-2D MoS₂ layers, it is worth mentioning that noble metals such as Au are also dissolvable in various buffer solutions, which can release chloride ions in a bio-friendly manner [67]. For XPS measurements, all spectra were referenced to an Au (4f_{7/2}) binding energy of 84.0 eV and compared with previous studies from the National Institute of Standards and Technology photo-electron database [68–72].

4. Conclusion

In summary, we developed mechanically flexible VA-2D MoS₂/TOCN gas sensors and demonstrated their VOC gas sensing performances at room temperature. The gas sensors successfully detected four different tested gases of 100 ppm, including ethanol, methanol, acetone, and ammonia. They exhibited extremely high sensitivity, particularly for ethanol gas, surpassing previously explored 2D MoS₂-based sensors employing horizontally-aligned 2D layers. Furthermore, their intrinsic biodegradable and transient characteristics were demonstrated with various bio-friendly buffer solutions. This study broadens the versatility and applicability of VA-2D MoS₂ layers for futuristic unconventional device applications.

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Data availability statement

All data that support the findings of this study are included within the article (and any supplementary files).

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